

# Applications of MoS<sub>2</sub> as a Two-Dimensional Materials Beyond Graphene

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# Overview

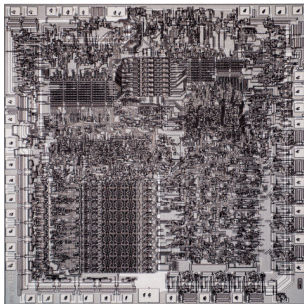
Origins and Discovery of Graphene

MoS<sub>2</sub> as Materials Beyond Graphene

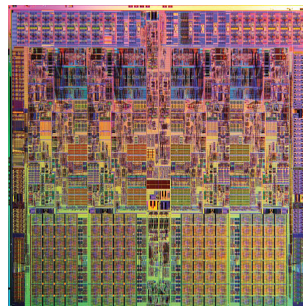
Applications of MoS<sub>2</sub> in FETs

Conclusion

# Motivations



**Figure:** The Intel 8080 introduced in 1974 consisted of approximately 5,000 transistors



**Figure:** The Intel Core i7 in 2008 consisted of approximately 731 million transistors

[Grifantini, 2008]

# Discovery of Graphene

# Properties of Graphene

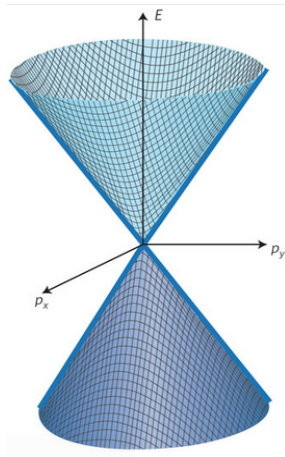


Figure: Electronic band structure of graphene [Fuhrer, 2010].

# Transition Metal Dichalcogenides

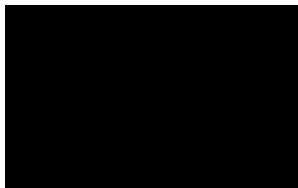


Figure: first figure

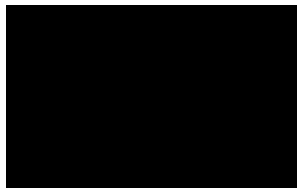


Figure: second figure

# Properties of MoS<sub>2</sub>

# Micromechanical Exfoliation



# MoS<sub>2</sub> in FETs

# MoS<sub>2</sub> in FETs Continued

# Outlook and Conclusion

# References



Fuhrer, M.S. (2010)

Graphene: Ribbons piece-by-piece

*Nature Materials* (9), 611–612.



Grifantini, K. (2008)

Moore's Law

*MIT Technology Review*

<http://www.technologyreview.com/photoessay/411485/moores-law/>.